NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

Rev. 7 — 18 November 2011

**Product data sheet** 

### 1. Product profile

#### 1.1 General description

NPN Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

#### Table 1. Product overview

Type number	Package	-			Package
	NXP JEITA JEDEC complement		complement	configuration	
PDTC114YE	SOT416	SC-75	-	PDTA114YE	ultra small
PDTC114YM	SOT883	SC-101	-	PDTA114YM	leadless ultra small
PDTC114YT	SOT23	-	TO-236AB	PDTA114YT	small
PDTC114YU	SOT323	SC-70	-	PDTA114YU	very small

#### 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design

#### **1.3 Applications**

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified
- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

#### 1.4 Quick reference data

#### Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	50	V
lo	output current		-	-	100	mA
R1	bias resistor 1 (input)		7	10	13	kΩ
R2/R1	bias resistor ratio		3.7	4.7	5.7	



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### 2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
SOT23; S	OT323; SOT416		
1	input (base)		
2	GND (emitter)	3	
3	output (collector)	2	1 R1 R2 sym007
SOT883			
1	input (base)		
2	GND (emitter)	1 3	
3	output (collector)	2 Transparent top view	1 R1 R2 sym007

### 3. Ordering information

Type number	Package	Package					
	Name	Description	Version				
PDTC114YE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
PDTC114YM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 $\times$ 0.6 $\times$ 0.5 mm	SOT883				
PDTC114YT	-	plastic surface-mounted package; 3 leads	SOT23				
PDTC114YU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

### 4. Marking

Table 5.         Marking codes           Type number         Image: Code State Stat	Marking code <sup>[1]</sup>
PDTC114YE	33
PDTC114YM	DU
PDTC114YT	*27
PDTC114YU	*30

[1] \* = placeholder for manufacturing site code

PDTC114Y\_SER
Product data sheet

NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

### 5. Limiting values

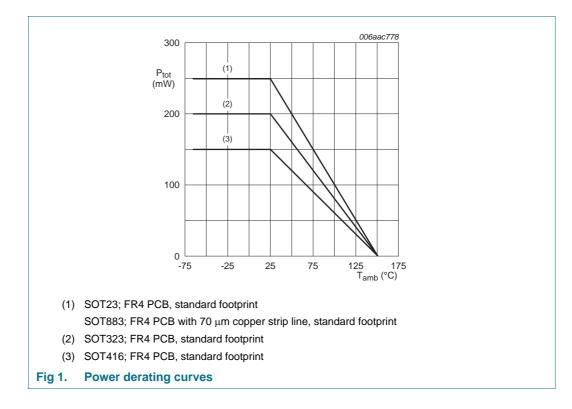
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	6	V
VI	input voltage				
	positive		-	+40	V
	negative		-	-6	V
I <sub>O</sub>	output current		-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; $t_p \leq 1 ms$	-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PDTC114YE (SOT416)		<u>[1][2]</u> _	150	mW
	PDTC114YM (SOT883)		[2][3]	250	mW
	PDTC114YT (SOT23)		<u>[1]</u> _	250	mW
	PDTC114YU (SOT323)		<u>[1]</u> -	200	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 µm copper strip line, standard footprint.

NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 



### 6. Thermal characteristics

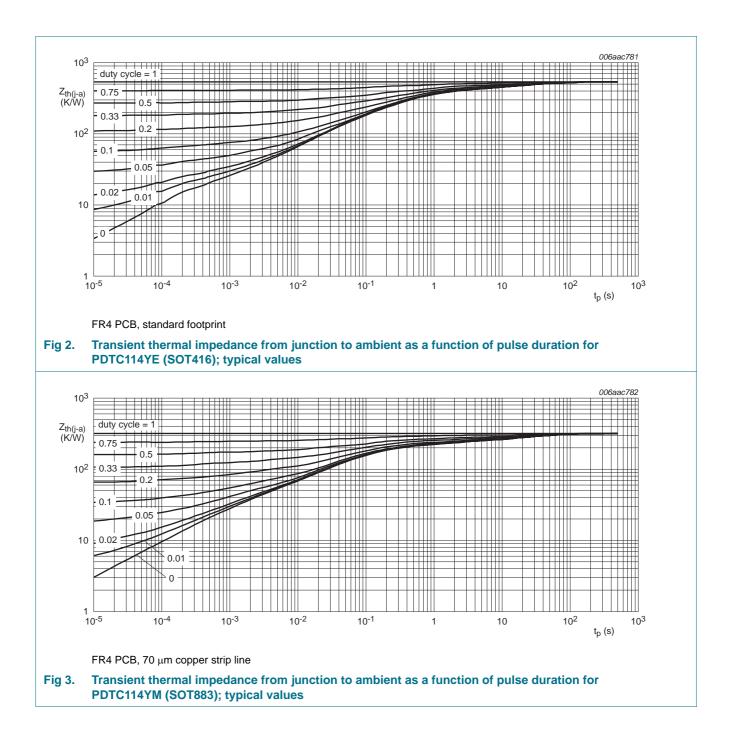
Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air				
	PDTC114YE (SOT416)		<u>[1][2]</u>	-	830	K/W
	PDTC114YM (SOT883)		[2][3]	-	500	K/W
	PDTC114YT (SOT23)		<u>[1]</u> -	-	500	K/W
	PDTC114YU (SOT323)		<u>[1]</u> -	-	625	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

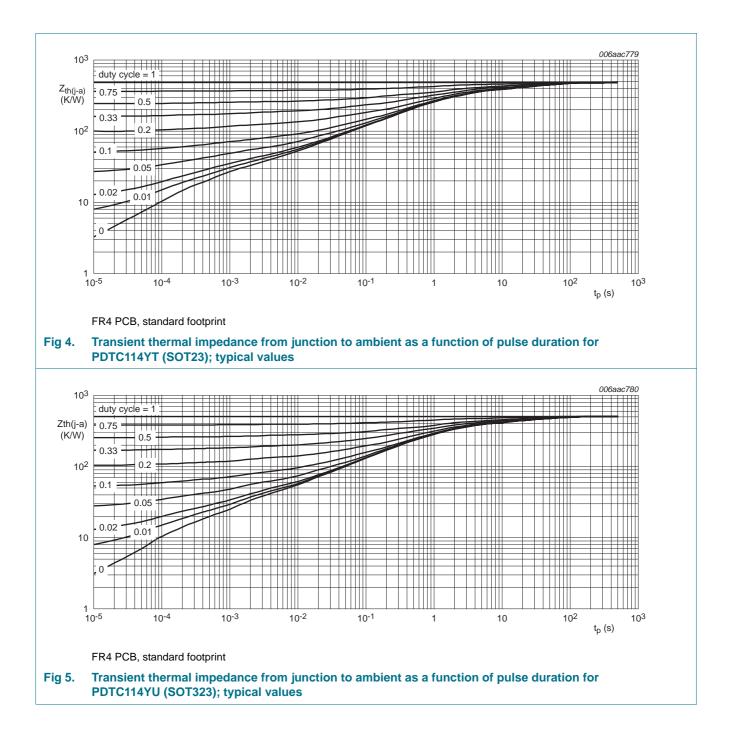
[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70  $\mu$ m copper strip line, standard footprint.

# **PDTC114Y series**



# **PDTC114Y series**

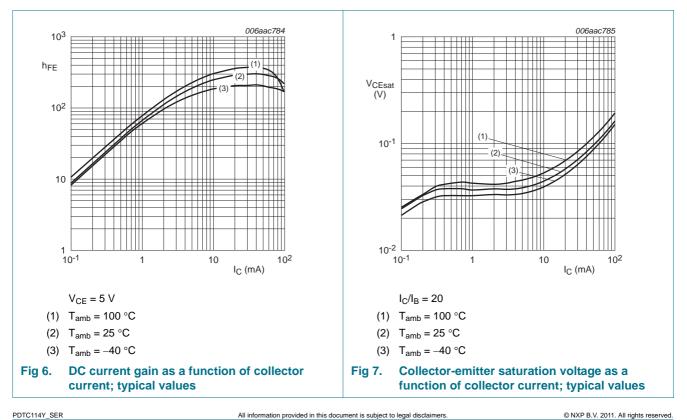


NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

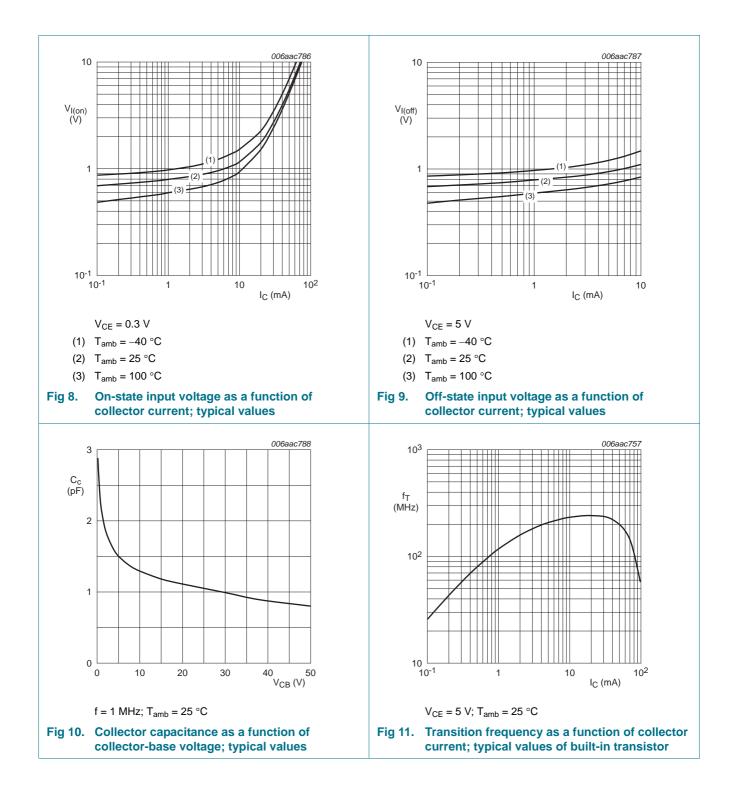
#### **Characteristics** 7.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$		-	-	100	nA
I <sub>CEO</sub>	collector-emitter	$V_{CE} = 30 \text{ V}; I_B = 0 \text{ A}$		-	-	1	μA
	cut-off current	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	5	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	150	μA
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$		100	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C} = 5 \text{ mA}; I_{B} = 0.25 \text{ mA}$		-	-	100	mV
V <sub>I(off)</sub>	off-state input voltage	$V_{CE}$ = 5 V; $I_{C}$ = 100 $\mu$ A		-	0.7	0.5	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 1 \text{ mA}$		1.4	0.8	-	V
R1	bias resistor 1 (input)			7	10	13	kΩ
R2/R1	bias resistor ratio			3.7	4.7	5.7	
C <sub>c</sub>	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$		-	-	2.5	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA; f = 100 MHz	<u>[1]</u>	-	230	-	MHz

[1] Characteristics of built-in transistor



# **PDTC114Y series**



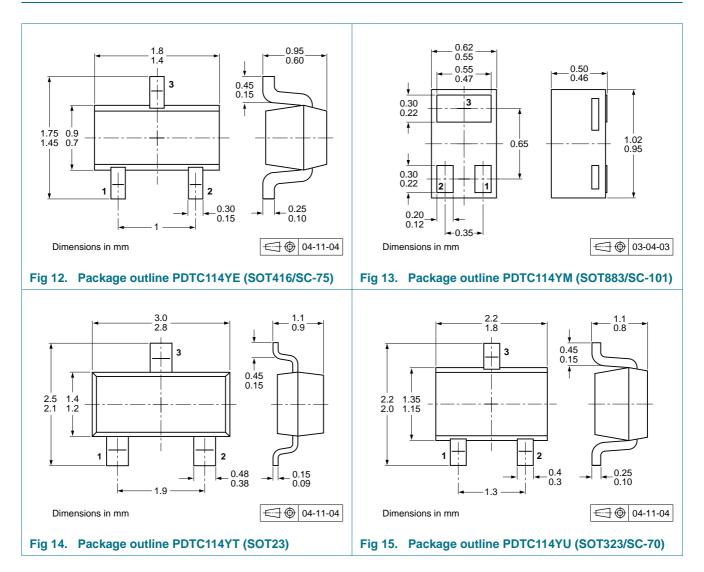
NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

### 8. Test information

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

### **10. Packing information**

#### Table 9. Packing methods

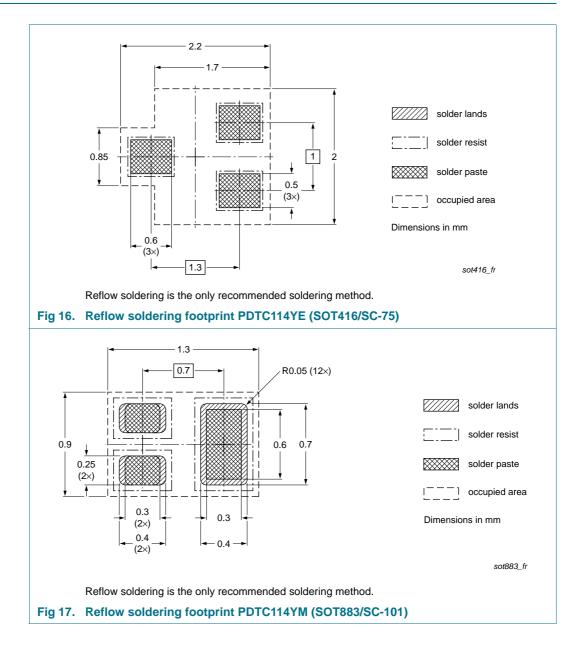
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

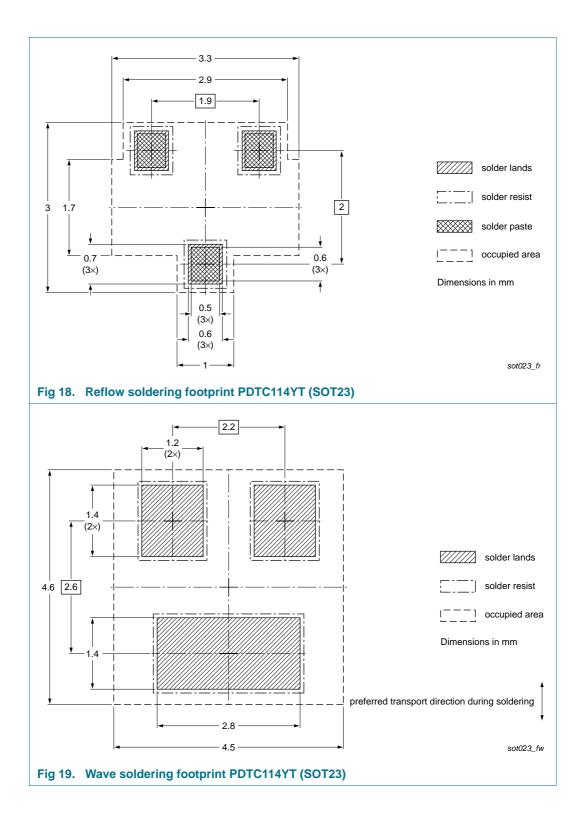
Type number	Package	Description	Packing	Packing quantity		
			3000	5000	10000	
PDTC114YE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTC114YM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
PDTC114YT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
PDTC114YU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	

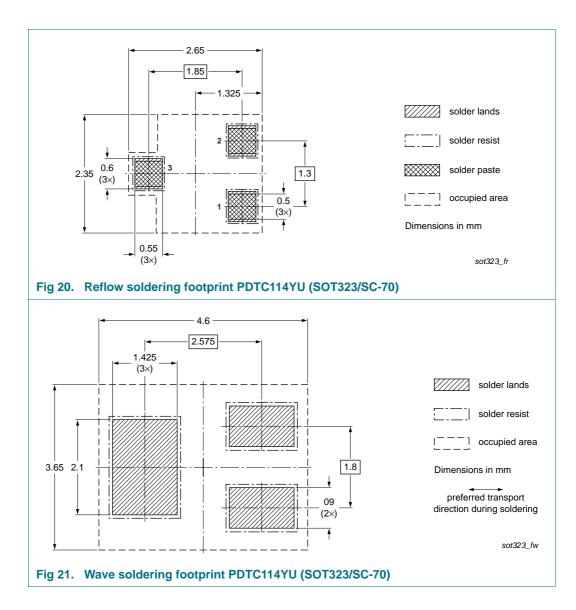
[1] For further information and the availability of packing methods, see <u>Section 14</u>.

NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

### 11. Soldering







### NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$

### 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
PDTC114Y_SER v.7	20111118	Product data sheet	-	PDTC114Y_SERIES v.6			
Modifications:	<ul> <li>The format of this document has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>						
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>						
	<ul> <li>Type numbers PDTC114YEF, PDTC114YK and PDTC114YS removed.</li> </ul>						
	<u>Section 1 "Product profile"</u> : updated						
	<u>Section 3 "Ordering information"</u> : added						
	<u>Section 4 "Marking</u> ": updated						
	• Figure 1 to 11: added						
	<ul> <li>Section 5 "Limiting values": updated</li> </ul>						
	Section 6 "Thermal characteristics": updated						
	<ul> <li>Table 8 "Characteristics": V<sub>i(on)</sub> redefined to V<sub>I(on)</sub> on-state input voltage, V<sub>i(off)</sub> redefined to V<sub>I(off)</sub> off-state input voltage, I<sub>CEO</sub> updated, f<sub>T</sub> added</li> </ul>						
	Section 8 "Test information": added						
	Section 9 "Package outline": superseded by minimized package outline drawings						
	Section 10 "Packing information": added						
	Section 11 "Soldering": added						
	Section 13 <sup>c</sup>	Legal information": updated	1				
PDTC114Y_SERIES v.6	20040817	Product data sheet	-	PDTC114Y_SERIES v.5			
PDTC114Y_SERIES v.5	20040910	Product specification	-	PDTC114Y_SERIES v.4			
PDTC114Y SERIES v.4	20030414	Product specification	-	-			

# Table 10 Pevision history

### **13. Legal information**

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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#### NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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# **PDTC114Y series**

NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

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